NSN 5961-01-191-3356

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-191-3356 **Inclosure Material:** Glass and metal **Overall Length:** 1.453 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.7 forward voltage, peak and 800.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 60.00 amperes forward current, average and 5.00 milliamperes repetitive peak reverse current **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No